

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1	"6696324".pn.	USPAT	OR	OFF	2007/12/21 21:21
S2	28	("5185294" "5289030" "5313090" "5340761" "5403772" "5573959" "5677240" "5734177" "5837619" "5969377" "6017779" "6043512" "6159779" "6218206" "6274412" "6287899" "6338988" "6340610" "6362028" "6395586").PN. OR ("6696324").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/12/21 21:28
S3	3	"5978058".pn. or "6444296".pn. or "5181132".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/12/21 21:30
S4	73	257/E29.151	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/25 17:59
S5	82	257/E51.005	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/25 18:00
S6	3698	257/72	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/25 18:02
S7	1173	257/208	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/25 18:28
S8	819	257/765	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/25 18:28

EAST Search History

S9	10	(semiconductor or die or dice or chip or IC) and pad near ("Al" or aluminum) and ("TFT" or thin near film near transistor) and gate and gate near (insulat\$3 or dielectric) and (transparent\$3 or translucent\$3) near (conduct\$3)	USPAT	OR	ON	2007/12/25 18:53
S10	151	(semiconductor or die or dice or chip or IC) and (pad or wir\$3) near ("Al" or aluminum) and ("TFT" or thin near film near transistor) and gate and gate near (insulat\$3 or dielectric) and (transparent\$3 or translucent\$3) near (conduct\$3)	USPAT	OR	ON	2007/12/25 19:37
S11	43	("5478766" "5686976" "5844255" "5852488" "6146796" "6156583" "6172733").PN. OR ("6255130").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/12/25 19:34
S12	779	(semiconductor or die or dice or chip or IC) and (pad or wir\$3 or metal) near ("Al" or aluminum) and ("TFT" or thin near film near transistor) and gate and gate near (insulat\$3 or dielectric) and (transparent\$3 or translucent\$3) near (conduct\$3)	USPAT	OR	ON	2007/12/25 20:10
S13	628	S12 not S10	USPAT	OR	ON	2007/12/25 20:05
S14	1	"6008065".pn.	USPAT	OR	ON	2007/12/25 20:06
S15	227	(semiconductor or die or dice or chip or IC) and (pad or wir\$3 or metal) near ("Al" or aluminum) same (cap\$4 or cover\$3 or coat\$3 or plat\$3 or second or upper or top) with ("Al" or aluminum) and ("TFT" or thin near film near transistor) and gate and gate near (insulat\$3 or dielectric) and (transparent\$3 or translucent\$3) near (conduct\$3)	USPAT	OR	ON	2007/12/25 20:12